

This product is obsolete.

This information is available for your convenience only.

For more information on Zarlink's obsolete products and replacement product lists, please visit

http://products.zarlink.com/obsolete_products/



200MHz DIRECT CONVERSION FSK DATA RECEIVER

The SL6649-1 is a low power direct conversion radio receiver for the reception of frequency shift keyed transmissions. It features the capability of 'power down' for battery conservation.

The device also includes a low battery flag indicator.

FEATURES

- Very Low Power Operation typ. 3.7mW
- Single Cell Operation with External Inverter
- Complete Radio Receiver in One Package
- Operation up to 200MHz
- 100nV Typical Sensitivity
- Operates up to 1200 BPS
- On Chip Tunable Active Filters
- Minimum External Component Count
- Low Power Down Current Typical 5µA

APPLICATIONS

- Low Power Radio Data Receiver
- Wristwatch Credit Card Pager
- Radio Paging
- Ultrasonic Direction Indication
- Security Systems
- Remote Control Systems

ABSOLUTE MAXIMUM RATINGS

Supply Voltage 6V Storage Temperature -55°C to +150°C

Operating Temperature -20°C to +70°C

ORDERING INFORMATION

SL6649-I/KG/MPES - Small outline (MP28) supplied in tubes

SL6649-1/KG/MPEF - Small outline (MP28)

supplied in tape & reel

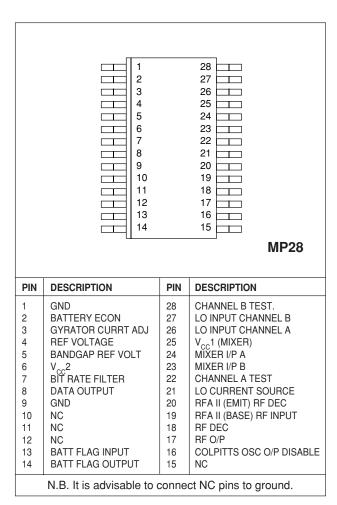


Figure 1: Pin Connections - Top View

ELECTRICAL CHARACTERISTICS

These characteristics are guaranteed over the following conditions (unless otherwise stated). $T_{amb}=25^{\circ}C,\ V_{CC}1=2.5V,\ V_{CC}2=3.5V$

		Value				
Characteristic	Pin	Min	Тур	Max	Units	Conditions
Supply Voltage V _{CC} 1	25	V _R	1.3	2.8	V	$V_{CC}1 \le (V_{CC}2)-0.7$
Supply Voltage V _{CC} 2	6,16	1.8	2.3	3.5	V	
Supply Current I _{CC} 1	17, 25,		1.6	2.0	mA	
	26, 27					(I _{BF}) Included
Supply Current I _{CC} 2	6,16		0.65	0.80	mA	
Power Down I _{CC} 1	17, 21, 25,		5	12	μΑ	Batt Econ Low
	26, 27					
Power Down I _{CC} 2	6,16		3	12	μΑ	Batt Econ Low
Bandgap Reference	5	1.15	1.22	1.35	V	
Voltage Reference	4	0.93	1.0	1.13	V	
RF Amplifier						
Supply Current (I _{RF})	17	430	535	640	μΑ	
Power Down	17	400	000	040	μΑ	Included in Power Down I _{cc} 1
Tower Bown	.,				μι	melada iir awai zawi icc
Mixers						
Gain to "IF Test"		32		38	dB	L.O. inputs driven in parallel
						with 50mV RMS @ 50MHz.
						IF = 2kHz
Oscillator						
Current Source	21	215	270	330	μA	
Power Down	21				μΑ	Included in Power Down I _{cc} 1
Decoder						
Sensitivity				40	μVrms	Signal injected at "IF TEST"
					ρ	B.E.R. ≤1 in 30
						5kHz deviation @ 500 bits/sec
						BRF capacitor = 1nF
Output Mark Space Ratio	8	7:9		9:7		
Output Logic High	8	85			%V _{cc} 2	
Output Logic Low				15	%V _{cc} 2	
Battery Economy		() (() () ()				5
Input Logic High	2	(V _{CC} 2)-0.3		0.0	V	Powered Up
Input Logic Low	2		0.05	0.3	V	Powered Down
Input Current			0.05	1	μΑ	
Battery Flag						
Output High Level	14	85			%V _{cc} 2	Battery Low R _I > 1MΩ
Output Low Level	14			15	%V _{CC} 2 V	Battery High R _L > 1 MΩ
Flag trig Level	13	V _R -25mV		V _R +25mV	V	Voltage Reference (V _R) pin 4
Colpitts Oscillator		4.5				D 001/ 1 0 1 01/D
Frequency		15			kHz	R=90K, pin 3 to GND
				15	kHz	R=360K, pin 3 to GND

TYPICAL ELECTRICAL CHARACTERISTICS

These characteristics are guaranteed by design.

 $T_{amb} = 25^{\circ}C, V_{CC}1 = 2.5V, V_{CC}2 = 3.5V$

		Value				
Characteristic	Pin	Min	Тур	Max	Units	Conditions
RF Amplifier Noise Figure Power Gain Input Impedance	19		5.5 14		dB dB	$RS = 50\Omega$ See Fig. 8
Mixer RF Input Impedance LO Input Impedance LO DC Bias Voltage	23, 24 26, 27 26, 27				V	See Figs. 9 (a) and (b) See Fig. 10 Equal to pin 25
Detector Output Current	7		±4		μА	
Colpitts Oscillator Frequency Output Voltage	16 16		15 20		kHz mVp-p	R = 270K, Pin 3 to GND R _L >> 1MΩ N.B. Refer to Channel Filter Fig. 4

RECEIVER CHARACTERISTICS (GPS DEMONSTRATION BOARD)

Measurement conditions (unless otherwise stated): Applications circuit diagram Fig.6; V_{CC} 1 = 1.3V; V_{CC} 2 = 2.3V; V_{CC} 3 = 25°C; Colpitts oscillator resistor = 270kΩ; mixer input A and B phase balance = 180°; local oscillator input A and B phase balance = 90°. Measurement methods as described by CEPT Res 2 specification. F_{IN} = 153MHz (512 baud).

	Value				
Characteristic	Min	Тур	Max	Units	Conditions
Terminal Sensitivity Tone only 4/5 call reception		-127	-124	dBm	$\Delta f = 4.5 \text{kHz}, R_S = 50\Omega$
Deviation Acceptance		±2.5		kHz	3dB De-Sensitisation. $F_{IN} = F_{LO}$
Centre Frequency Acceptance	±2.0	±2.5		kHz	$\Delta f = 4.5 \text{kHz}$
Adjacent Channel Rejection	65	70		dB	Δf = 4.5kHz Channel Spacing 25kHz
Adjacent + 1 Channel Rejection	65	70		dB }	External capacitors on test
Third Order Intermod adj-1 + adj-2	52	53		dB	pins A and B.

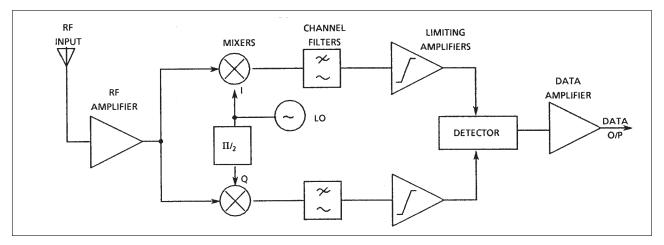


Figure 2: Block Diagram of SL6649-1 Direct Conversion Receiver

PRINCIPLE OF OPERATION

The incoming signal is split into two parts and frequency converted to baseband. The two paths are produced in phase quadrature (see Fig 2) and detected in a phase detector which provides a digital output. The quadrature network must be in the local oscillator path.

At a data rate of 512 baud and a deviation frequency of $4.5 \mathrm{kHz}$, the input to the system has a demodulation index of 18. This gives a spectrum as in Fig 3. f_1 and f_0 represent the 'steady state' frequencies (i.e. modulated with continuous '1' and '0' respectively). The spectrum in Fig 3 is for reversals (a 0-1-0-1-0-1 etc. pattern) at the system bit rate; f_C is the nominal carrier frequency).

When the LO is at the nominal carrier frequency, then a continuous '0' or '1' will produce an audio frequency, at the output of the mixers corresponding to the difference between f_0 and f_C or f_1 and f_C . If the LO is precisely at fc, then the resultant output signal will be at the same frequency regardless of the data state; nevertheless, the relative phases of the two paths will reverse between '0' and '1' states. By applying the amplified outputs of the mixers to a phase discriminator, the digital data is reproduced.

TUNING THE CHANNEL FILTERS

The adjacent channel rejection performance of the SL6649-1 receiver is determined by the channel filters. To obtain optimum adjacent channel rejection, the channel filters' cut off frequency should be set to 8kHz. The process tolerances are such that the cut off frequency cannot be accurately defined, hence the channel filters must be tuned. However the receiver characteristics on the previous page can be achieved with a fixed $270k\Omega$ resistor between pin 3 and GND.

Tuning is performed by adjusting the current in the gyrator circuits. This changes the values of the gyrator's equivalent inductance. The cut off frequency is tuned to 8kHz. To accurately define the cut off of the channel filters, a gyrator based Colpitts oscillator circuit has been included on the SL6649-1. The Colpitts oscillator and channel filters use the same type of architecture, hence there is a direct correlation between oscillator frequency and cut off frequency. By knowing the Colpitts oscillator frequency the channel filter cut off frequency can be estimated from Figure 4.

Once the channel filters have been tuned it may be necessary to disable the Colpitts oscillator. The Colpitts oscillator is disabled by connecting the Colpitts oscillator output/disable pin (pin # 16) to V_{CC}2. This is needed since the Colpitts oscillator may impair the performance of the receiver.

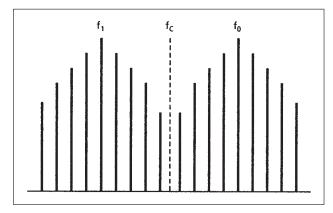


Figure 3: Spectrum Diagram

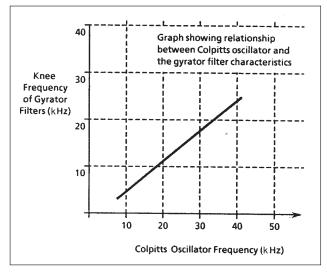


Figure 4

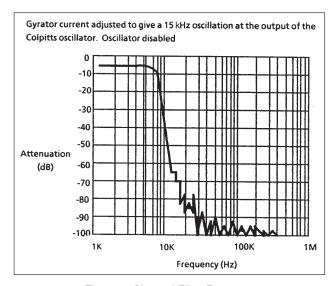


Figure 5: Channel Filter Response

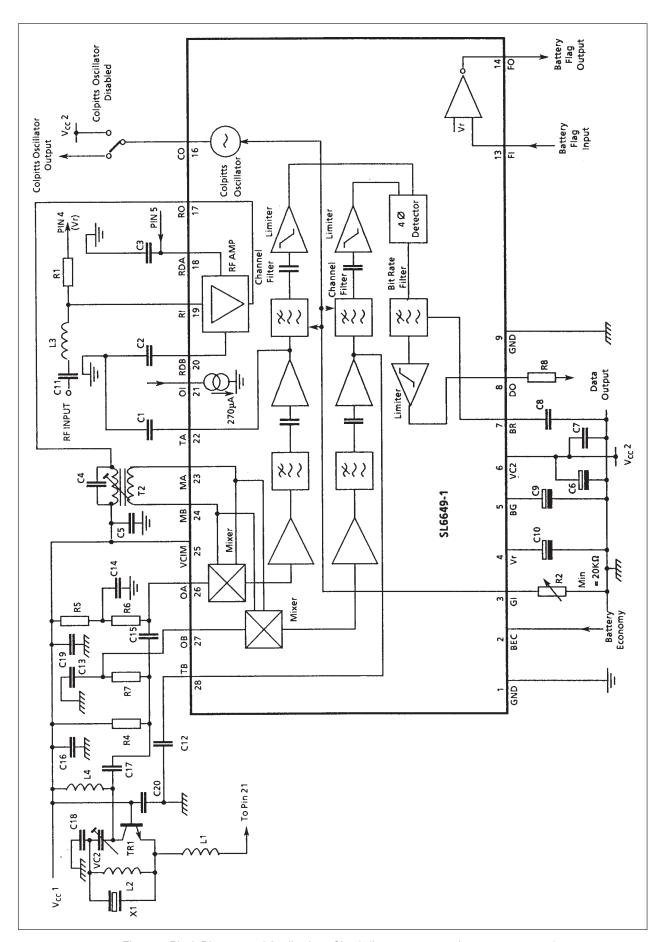


Figure 6: Block Diagram and Applications Circuit (for component values see next page)

COMPONENTS LIST FOR FIGURE 6

Capa	acitors			Res	istors	Ind	uctors	Trai	nsformers	Mis	cellaneous
C1 C2 C3 C4 C5 C6 C7 C8 C9 C10	1nF 1nF 1nF 5.6pF 1nF 2.2μF 1nF 2.2μF 2.2μF	C14 C15	1nF 1nF 10pF 1nF 10pF 1nF 5.6pF 4.7pF 1nF	R1 R2 R4 R5 R6 R7 R8	$2.2k\Omega$ $500k\Omega$ Variable 100Ω 100Ω 100Ω 100Ω 100Ω $100K\Omega$	L1 L2 L3 L4	10µH 220nH 150nH 100nH	T1	1:1 Transformer Primary/Secondary Inductance=200nH	X1	SL6649-1 SOT-23 Transistor with $f\tau \ge 1.3 GHz$ (EG. ZETEX BFS 17) 153MHz 7th overtone crystal 2 1.5-10pF

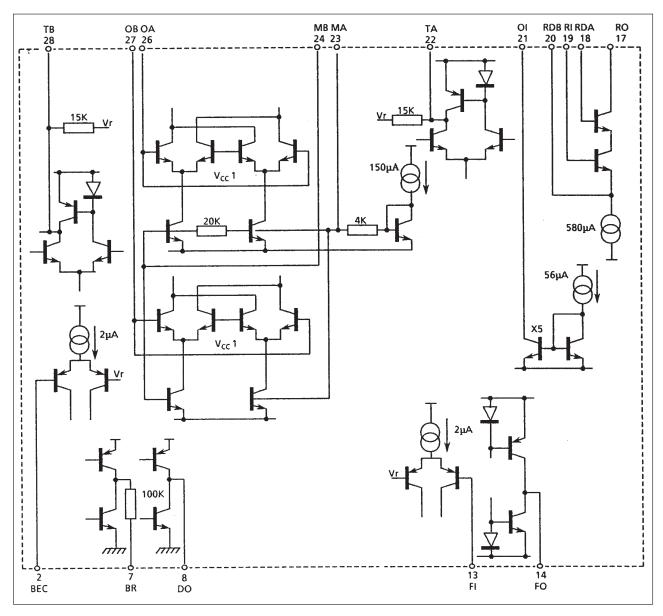


Figure 7: Pinning Diagram of the SL6649-1

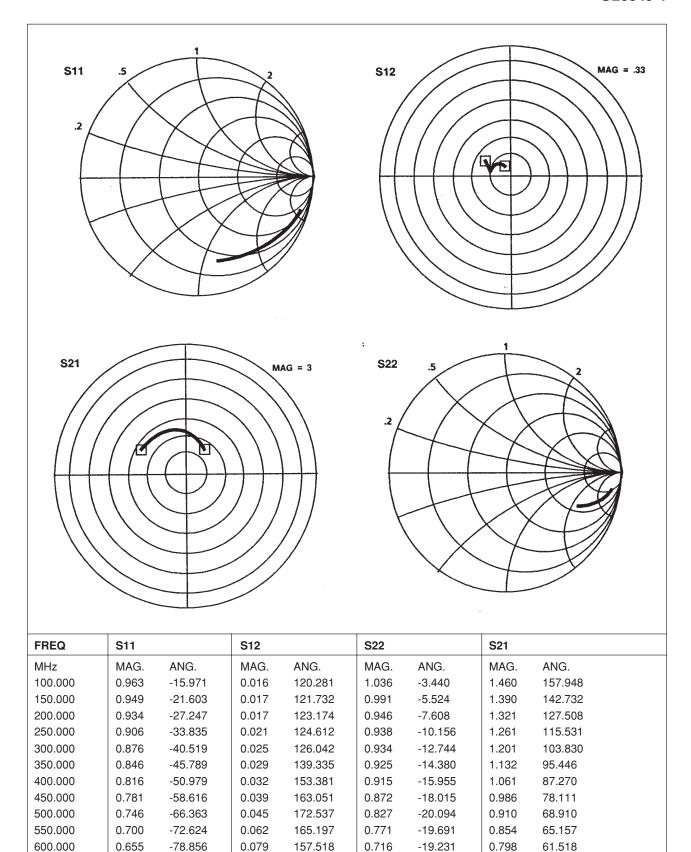


Figure 8: RF Amplifier

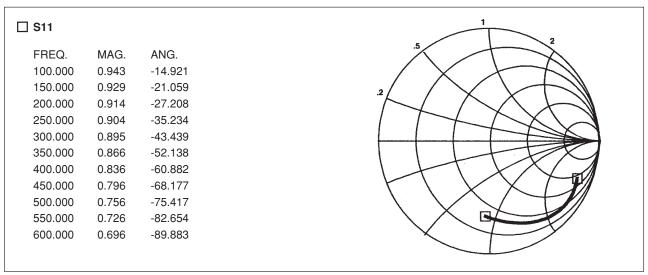


Figure 9a: SL6649-1 Mixer RF input pin 23

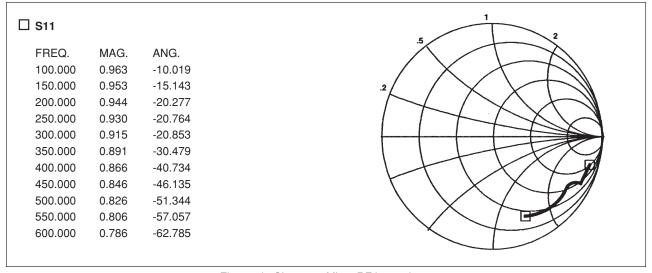


Figure 9b: SL6649-1 Mixer RF input pin 24

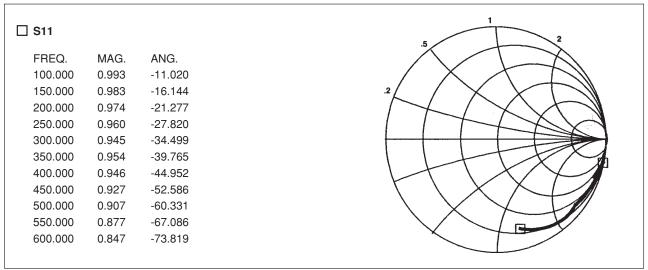


Figure 10: SL6649-1 Mixer LO input pins 26 and 27

METHOD FOR THE MEASUREMENT OF SENSITIVITY ON THE SL6649-1 RECEIVER

The method used by GEC Plessey Semiconductors in the measurement of terminal sensitivity is essentially the same as that described in the CEPT Res 2 Specification.

This method requires the following equipment:

- 1. A signal generator e.g. HP8640
- 2. A pocsag encoder
- 3. A pocsag decoder e.g. MV6639
- 4. An SL6649-1 Demo Board.
- 5. An interference free low impedance P.S.U. ($V_{CC}1$ and $V_{CC}2$ must be separate supplies and there must be at least 0.7V difference between them). Recommended supply configurations are shown in Fig. 13.

The test equipment and D.U.T. are set up as shown in Figure 11.

The R.F. frequency is set to the nominal L.O. frequency of the receiver and the peak deviation is set to 4.5kHz.

Care must be taken to avoid long power supply leads and any ground loops. Any interference from the decoder will be reduced by the insertion of a high value resistor R1 ($100K\Omega$) between the receiver data output and the decoder input.

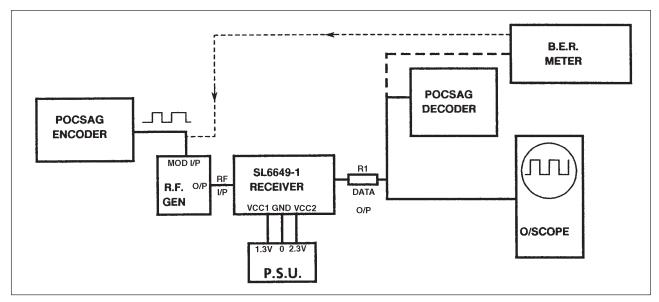


Figure 11: Test System

The generator output level is reduced successively until the decoder responds just 4 out of 5 times to the encoder signal. This output level is then recorded as the sensitivity threshold of the receiver.

We find that this threshold correlates to a bit error rate of 1 in 30. The data output waveforms for an input level which produces a B.E.R. of 1 in 30 and for input levels 2dB above and below this level, are shown below (square wave input). It can be seen that the edge jitter increases dramatically at signal levels below the sensitivity threshold of -127dBm. Typical waveforms that can be seen on an oscilloscope around the sensitivity threshold level are shown in Figure 12.

NB. In performing the sensitivity measurement great care should be taken in preventing coupling between test leads.

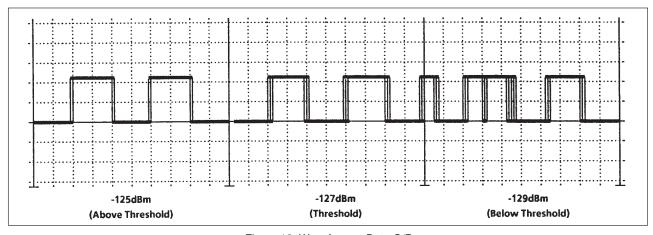


Figure 12: Waveform at Data O/P

PIN	MNEMONIC	FUNCTION
1	GND	Ground
2	BEC	Battery Economy
3	GI	Gyrator Current Adjust
4	Vr	Reference Voltage
5	BG	Bandgap Reference Voltage
6	Vc2	V _{CC} 2
7	BR	Bit rate Filter
8	DO	Data Output
9	GND	Ground
10		UNC
11		UNC
12		UNC
13	FI	Battery Flag Input
14	FO	Battery Flag Output

PIN	MNEMONIC	FUNCTION
15		UNC
16	CO	Colpitts Oscillator
		Output/Disable
17	RO	RFA I (collector) RF Output
18	RDA	RFA I (base) RF Decouple
19	RI	RFA II (base) RF Input
20	RDB	RFA II (emitter) RF Decouple
21	Ol	LO Current Source
22	TA	Channel A Test
23	MA	Mixer I/P B
24	MB	Mixer I/P A
25	VCIM	V _{CC} 1 (mixer)
26	OA	LÕ Input Channel A
27	OB	LO Input Channel B
28	TB	Channel B Test

POWER SUPPLIES

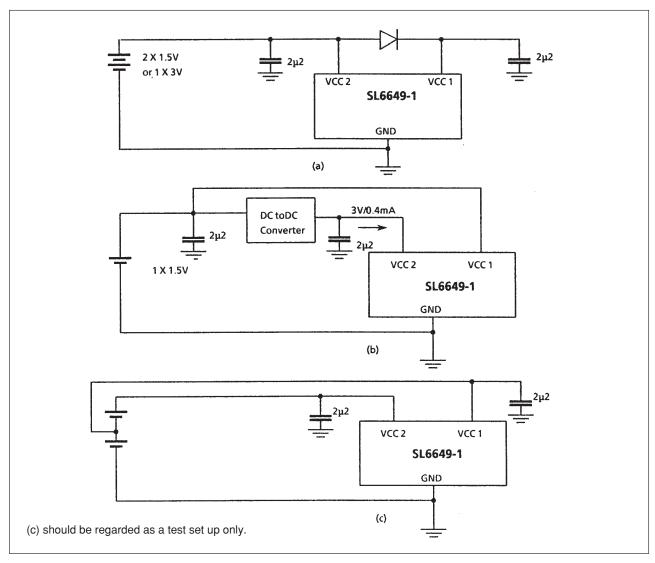


Figure 13(a): SL6649-1 Power Supply Options

PAGER APPLICATION EXAMPLE

A typical 1 volt pager system suitable as a wrist watch application is shown in Figure 13 (b). Only 3 integrated circuits are required to perform all the functions of a tone only pager. These are SL6649-1 direct conversion radio receiver and the MV6639 POCSAG decoder plus a 1 volt E²PROM (eg. Seiko Epson SPM28C51).

The SL6649-1 receives and demodulates the data, and monitors the battery voltage. The interface between the decoder and receiver consists of only 3 connections excluding the supplies.

The MV6639 performs all the functions required for a POCSAG decoder for tone only and/or pager messaging at 512 or 1200 baud. A 32kHz watch crystal is used as the reference frequency for the decoder.

The decoder voltage doubler output $V_{\rm CC}2$ is available to power not only the receiver, but an alternative higher voltage E²PROM and microprocessor/LCD driver for a full tone and message pager.

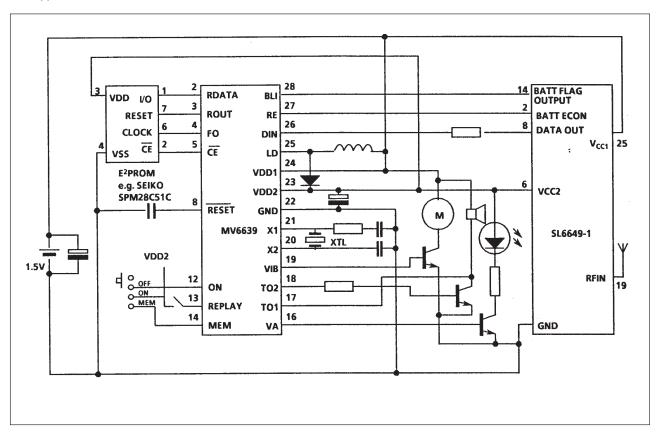


Figure 13(b): Tone Pager Applications Example Showing Interface with SL6649-1 Receiver

OPERATION AT OTHER FREQUENCIES AND DATA RATES

The values given in the components list for figure 6 are appropriate for frequencies nominally around 153MHz. In order to use the receiver at other frequencies it is necessary to change the capacitor C4 which is resonant with the transformer T1, and L2 and L4 in the oscillator circuit.

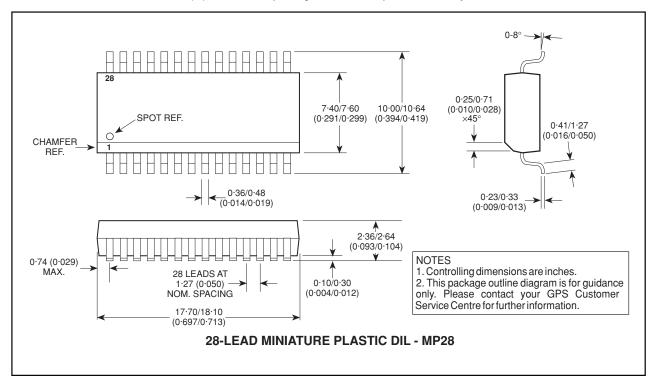
It is also necessary to change the values of capacitors C13 and C15 such that the reactance of these is equal to 100 Ω at the required frequency.

It is of course necessary to use a crystal of the required frequency and stability. In order to use the receiver at higher data rates it is only necessary to reduce the value of C8, for example, at 1200bps, C8=470pf.

A demonstration board has been designed specifically to demonstrate terminal sensitivity. It is possible to connect an antenna to the board with suitable matching but no guarantee can be given regarding field strength sensitivity. However, with a suitably designed combination of PCB and antenna, a sensitivity of $5\mu V/M$ should be attainable.

PACKAGE DETAILS

Dimensions are shown thus: mm (in). For further package information, please contact your local Customer Service Centre.





HEADQUARTERS OPERATIONS GEC PLESSEY SEMICONDUCTORS

Cheney Manor, Swindon. Wiltshire SN2 2QW, United Kingdom. Tel: (01793) 518000 Fax: (01793) 518411

GEC PLESSEY SEMICONDUCTORS

P.O. Box 660017 1500 Green Hills Road, Scotts Valley, California 95067-0017, United States of America. Tel: (408) 438 2900 Fax: (408) 438 5576

CUSTOMER SERVICE CENTRES

- FRANCE & BENELUX Les Ulis Cedex Tel: (1) 69 18 90 00 Fax: (1) 64 46 06 07
- GERMANY Munich Tel: (089) 3609 06-0 Fax: (089) 3609 06-55
- ITALY Milan Tel: (02) 66040867 Fax: (02) 66040993
- **JAPAN** Tokyo Tel: (03) 5276-5501 Fax: (03) 5276-5510
- NORTH AMERICA Scotts Valley, USA Tel (408) 438 2900 Fax: (408) 438 7023.
- SOUTH EAST ASIA Singapore Tel: (65) 3827708 Fax: (65) 3828872
- **SWEDEN** Stockholm Tel: 46 8 702 97 70 Fax: 46 8 640 47 36
- TAIWAN, ROC Taipei Tel: 886 2 5461260. Fax: 886 2 7190260 UK, EIRE, DENMARK, FINLAND & NORWAY

Swindon Tel: (01793) 518527/518566 Fax: (01793) 518582

These are supported by Agents and Distributors in major countries world-wide.

© GEC Plessey Semiconductors 1995 Publication No. 3115 Issue No. 4.0 September 1995 TECHNICAL DOCUMENTATION - NOT FOR RESALE. PRINTED IN UNITED KINGDOM.

This publication is issued to provide information only which (unless agreed by the Company in writing) may not be used, applied or reproduced for any purpose nor form part of any order or contract nor to be regarded as a representation relating to the products or services concerned. No warranty or guarantee express or implied is made regarding the capability, performance or suitability of any product or service. The Company reserves the right to alter without prior notice the specification, design or price of any product or service. Information concerning possible methods of use its provided as a guide only and does not constitute any guarantee that such methods of use will be satisfactory in a specific piece of equipment. It is the wars' responsibility to fully determine the performance and suitability of any equipment using such information and to ensure that any publication or data used is up to date and has not been superseded. These products are not suitable for use in any medical products whose failure to perform may result in significant injury or death to the user. All products and materials are sold and services provided subject to the Company's conditions of sale, which are available on request



For more information about all Zarlink products visit our Web Site at www.zarlink.com

Information relating to products and services furnished herein by Zarlink Semiconductor Inc. or its subsidiaries (collectively "Zarlink") is believed to be reliable. However, Zarlink assumes no liability for errors that may appear in this publication, or for liability otherwise arising from the application or use of any such information, product or service or for any infringement of patents or other intellectual property rights owned by third parties which may result from such application or use. Neither the supply of such information or purchase of product or service conveys any license, either express or implied, under patents or other intellectual property rights owned by Zarlink or licensed from third parties by Zarlink, whatsoever. Purchasers of products are also hereby notified that the use of product in certain ways or in combination with Zarlink, or non-Zarlink furnished goods or services may infringe patents or other intellectual property rights owned by Zarlink.

This publication is issued to provide information only and (unless agreed by Zarlink in writing) may not be used, applied or reproduced for any purpose nor form part of any order or contract nor to be regarded as a representation relating to the products or services concerned. The products, their specifications, services and other information appearing in this publication are subject to change by Zarlink without notice. No warranty or guarantee express or implied is made regarding the capability, performance or suitability of any product or service. Information concerning possible methods of use is provided as a guide only and does not constitute any guarantee that such methods of use will be satisfactory in a specific piece of equipment. It is the user's responsibility to fully determine the performance and suitability of any equipment using such information and to ensure that any publication or data used is up to date and has not been superseded. Manufacturing does not necessarily include testing of all functions or parameters. These products are not suitable for use in any medical products whose failure to perform may result in significant injury or death to the user. All products and materials are sold and services provided subject to Zarlink's conditions of sale which are available on request.

Purchase of Zarlink's I²C components conveys a licence under the Philips I²C Patent rights to use these components in and I²C System, provided that the system conforms to the I²C Standard Specification as defined by Philips.

Zarlink, ZL and the Zarlink Semiconductor logo are trademarks of Zarlink Semiconductor Inc.

Copyright Zarlink Semiconductor Inc. All Rights Reserved.

TECHNICAL DOCUMENTATION - NOT FOR RESALE